## **Philips Components-Signetics**

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Memory Produ	cts

## DESCRIPTION

The 82S130 and 82S131 are field programmable, which means that custom patterns are immediately available by following the Signetics Generic I fusing procedure. The 82S130 and 82S131 devices are supplied with all outputs at logical Low. Outputs are programmed to a logic High level at any specified address by fusing the Ni-Cr link matrix.

These devices include on-chip decoding and 1 Chip Enable input for ease of memory expansion. They feature either Open Collector or 3-State outputs for optimization of word expansion in bused organizations.

Ordering information can be found on the following page.

The 82S130 and 82S131 devices are also processed to military requirements for operation over the military temperature range. For specifications and ordering information, consult the Signetics Military Data Handbook.

## BLOCK DIAGRAM

# 82S130 82S131 2K-bit TTL bipolar PROM

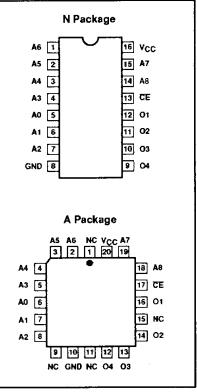
## FEATURES

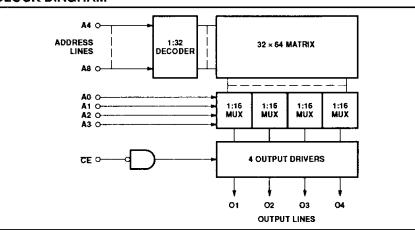
- Address access time: 50ns max
- Power dissipation: 0.3mW/bit typ
- Input loading: –100µA max
- On-chip address decoding
- One Chip Enable input
- Output options:
- N82S130: Open Collector
- N82S131: 3-State
- No separate fusing pins
- Unprogrammed outputs are Low level
- Fully TTL compatible

## APPLICATIONS

- Prototyping/volume production
- Sequential controllers
- Microprogramming
- Hardwired algorithms
- Control store
- Random logic
- Code conversion

## **PIN CONFIGURATIONS**





## 2K-bit TTL bipolar PROM (512 × 4)

## 82S130 / 82S131

#### **ORDERING INFORMATION**

DESCRIPTION	ORDER CODE		
16-Pin Plastic Dual-In-Line 300mil-wide	N82S130 N, N82S131 N		
20-Pin Plastic Leaded Chip Carrier 350mil-square	N82S130 A, N82S131 A		

#### **ABSOLUTE MAXIMUM RATINGS**

SYMBOL	PARAMETER	RATING	UNIT
Vcc	Supply voltage	+7.0	V <sub>DC</sub>
VIN	Input voltage	+5.5	V <sub>DC</sub>
V <sub>OH</sub>	Output voltage High (82S130)	+5.5	V <sub>DC</sub>
Vo	Output voltage Off-State (82S131)	+5.5	V <sub>DC</sub>
Tamb	Operating temperature range	0 to +75	°C
T <sub>stg</sub>	Storage temperature range	-65 to +150	°C

## DC ELECTRICAL CHARACTERISTICS 0°C $\leq$ Tamb $\leq$ +75°C, 4.75V $\leq$ V<sub>CC</sub> $\leq$ 5.25V

			LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS <sup>1,2</sup>	Min	Typ <sup>3</sup>	Max	UNIT
Input volt	age					
VIL	Low				0.8	v
V <sub>IH</sub>	High		2.0			V
VIC	Clamp	$I_{IN} = -12mA$			-1.2	<u>v</u>
Output vo	oltage					
		CE = Low				
VOL	Low	I <sub>OUT</sub> = 16mA			0.45	v
V <sub>OH</sub>	High (82S131)	$l_{OUT} = -2.0 \text{mA}$	2.4			V
Input curr	rent					
l <sub>IL</sub>	Low	V <sub>IN</sub> = 0.45V			-100	μA
liH	High	V <sub>IN</sub> = 5.5V			40	μΑ
Output cu	urrent					
lolk	Leakage (82S130)	CE = High, V <sub>OUT</sub> = 5.5V			40	μΑ
Inz	Hi-Z state (82S131)	$\overline{CE} = High, V_{OUT} = 5.5V$			40	μΑ
		$\overline{CE} = High, V_{OUT} = 0.5V$			-40	μΑ
los	Short circuit (B2S131) <sup>4</sup>	$\overline{CE} = Low, V_{OUT} = 0V$ , High stored	-15		-70	mA
Supply cu	urrent <sup>5</sup>					
lcc		V <sub>CC</sub> = 5.25V			140	mA
Capacita	nce					
		CE = High, V <sub>CC</sub> = 5.0V				
C <sub>IN</sub>	Input	$V_{IN} = 2.0V$		5		pF
COUT	Output	$V_{OUT} = 2.0V$		8		pF

#### NOTES:

1. Positive current is defined as into the terminal referenced.

1. Positive current is defined as this the terminal referenced 2. All voltages with respect to network ground. 3. Typical values are at  $V_{CC} = 5V$ ,  $T_{amb} = +25^{\circ}C$ . 4. Duration of short circuit should not exceed 1 second. 5. Measured with all inputs grounded and all outputs open.

## 2K-bit TTL bipolar PROM (512 × 4)

## 82S130 / 82S131

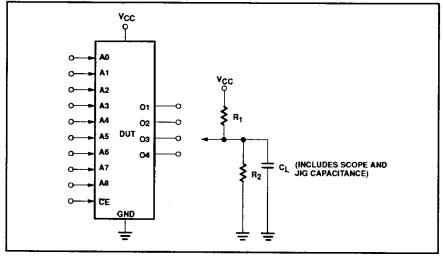
#### **AC ELECTRICAL CHARACTERISTICS**

 $R_1 = 270\Omega, R_2 = 600\Omega, C_L = 30 pF, 0^{\circ}C \le T_{amb} \le +75^{\circ}C, 4.75V \le V_{CC} \le 5.25V$ 

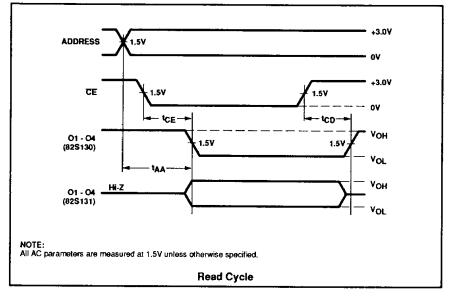
SYMBOL		то	FROM	LIMITS			
	PARAMETER			Min	Typ <sup>1</sup>	Max	UNIT
Access time	2		-		<b>I</b>		
t <sub>AA</sub>		Output	Address			50	ns
t <sub>CE</sub>		Output	Chip Enable			30	ns
Disable time	3		-	-	• • • • •		
tcp		Output	Chip Disable			30	ns

1. Typical values are at  $V_{CC} = 5V$ ,  $T_{amb} = +25^{\circ}C$ . 2. Tested at an address cycle time of 1 $\mu$ s. 3. Measured at a delta of 0.5V from Logic Level with  $R_1 = 750\Omega$ ,  $R_2 = 750\Omega$ ,  $C_L = 5pF$ .

#### **TEST LOAD CIRCUIT**



#### **VOLTAGE WAVEFORMS**



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